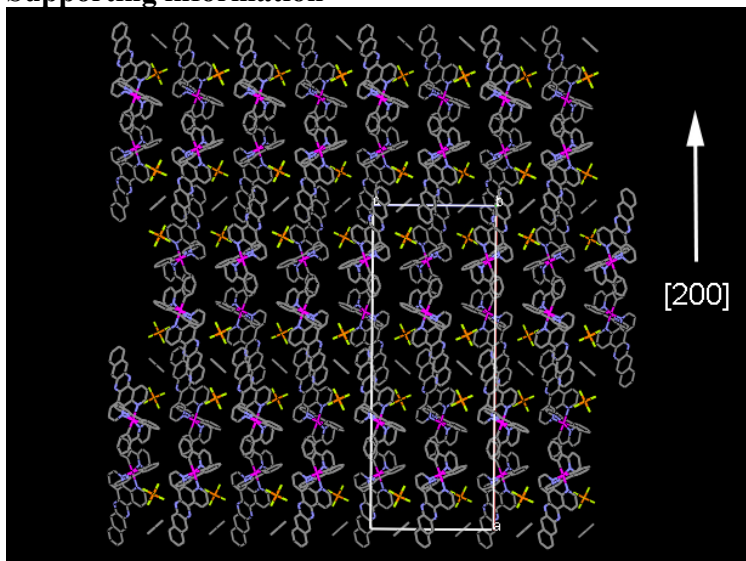
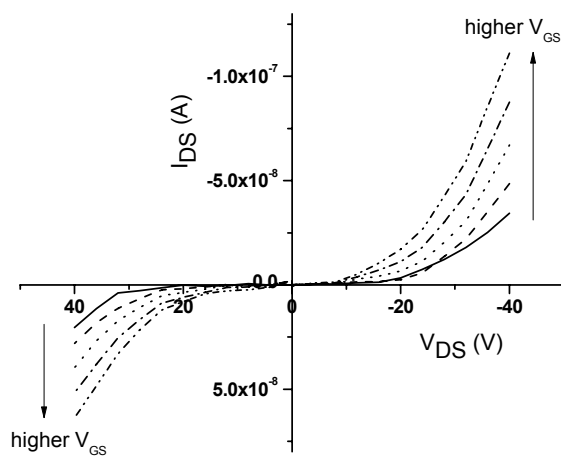


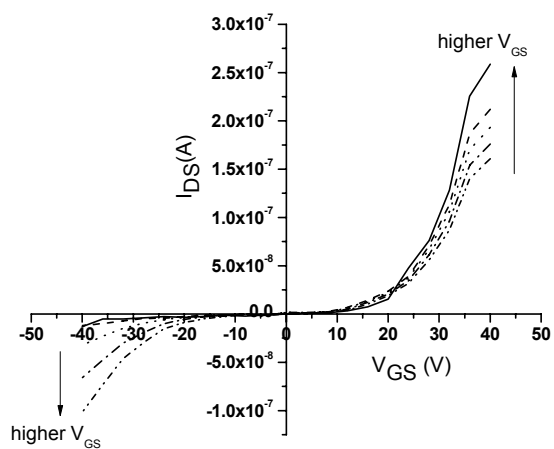
Supporting information



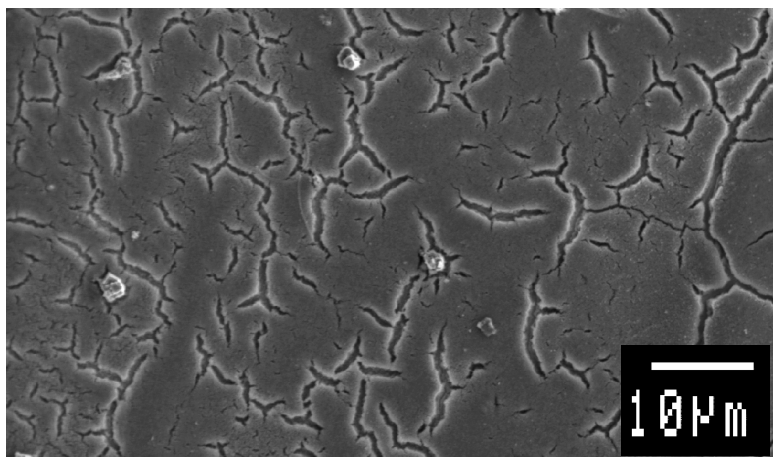
Crystal packing for complex 3 determined by single crystal X-ray diffraction.



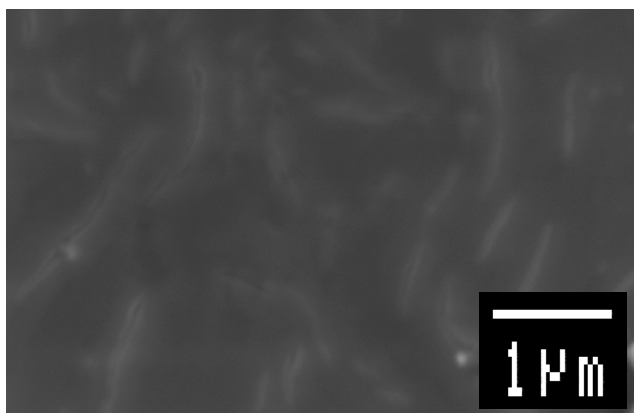
Output characteristics (I_{DS} versus V_{DS} at different V_{GS}) for the electrostatically aligned films of complex 1, whereas the gate voltage was increased in steps of 10 V.



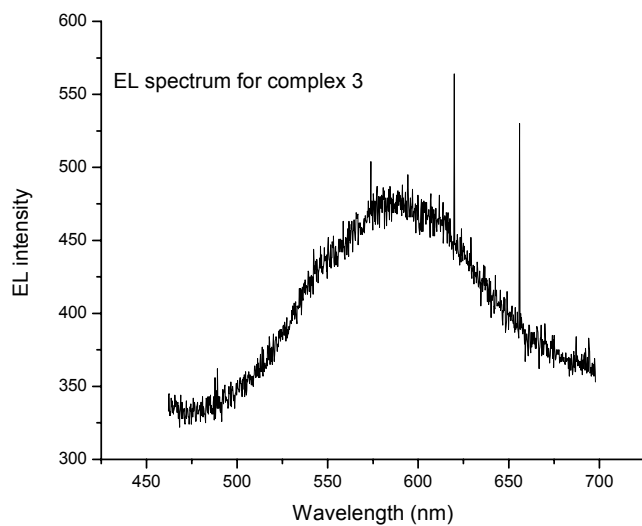
Output characteristics (I_{DS} versus V_{GS} at different V_{DS}) for the electrostatically aligned films of complex **2**, whereas the gate voltage was increased in steps of 10 V.



SEM image for the film of electrostatically aligned films of complex **2**.



SEM image for the film of electrostatically aligned films of complex **1**.



The EL spectrum for the device with complex **3**.